

Dynamic Engineers Inc.

2550 Gray Falls Dr., Suite#128, Houston, TX, 77077 TEL: 281-870-8822EMAIL:Sales@DynamicEngineers.com

H7 LC) ' \$\$GSgYf]Yg 10 to 52MHz

Temperature Compensated Crystal Oscillator

Features and Benefits

Frequency Range from 10 MHz to 52 MHz 5.0 mm x 3.2 mm ceramic SMD package
Up to ±0.5 ppm (depends on operating frequency and operating temperature)
HCMOS and Clipped Sine Wave(without DC-CUT capacitor) output optional 3.3V or 5.0V supply
Low power consumption
Low height and light weight
Compatible for automatic assembly

Typical Applications

WiMAX, WLAN Telecommunication Mobile phone

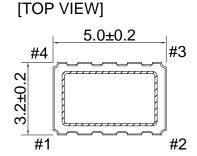
Description

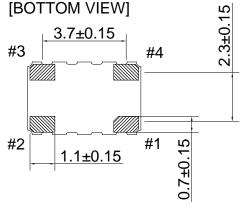
A new series of low power consumption temperature compensated crystal oscillators with the latest low noise integrated circuit topologies.

Mechanical Drawing & Pin Connections

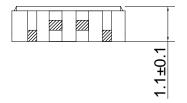
Drawing No:MD140026-3

Unit:mm 1mm=0.0394inch





[SIDE VIEW]



PIN FUNCTIONS

Pin	Funttion			
#1	VCON:VC-TCXO GND/NC:TCXO			
#2	GND			
#3	Output			
#4	VDD			



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Specifications

General Specifications							
Parameter	3.3V		5.0V				
		Min.	Max.	Min.	Max.		
Frequency Ran	ge	10MHz	52MHz	10MHz	26MHz		
Standard From	ionev	13.000000MHz, 14.400000MHz, 16.368000MHz, 16.369000MHz, 16.800000MHz,					
Standard Frequency		19.200000MHz, 19.680000MHz, 20.000000MHz, 26.000000MHz					
Frequency Tolerance*		_	±2.0ppm	_	±2.0ppm		
	(at 25°C, 1 hour after reflow)		±2.0ppm		±2.0ррпп		
Frequency Stat							
Vs Supply Voltage (±5%) change							
	Sine Wave	-	±0.2ppm	-	±0.2ppm		
	HCMOS		±0.4ppm	-	-		
Vs Load (±10%) change		-	±0.2ppm	-	±0.2ppm		
	Vs Aging (@1 st /year)		±1.0ppm	-	±1.0ppm		
Supply Voltage Variation		2.97V	3.63V	4.75V	5.25V		
(V _{DD}) ±5%		2.91 V	3.03 V	4.750	3.23 V		
Supply Current							
	Clipped Sine Wave						
10 MHz ≤ Fo ≤ 1		-	1.5mA	-	1.5mA		
15 MHz ≤ Fo ≤ 26 MHz		-	2.0mA	-	2.0mA		
26 MHz ≤ Fo ≤ 52 MHz		-	2.5mA	-	-		
HCMOS							
	10 MHz ≤ Fo ≤ 52 MHz		6.0	-	-		
Output Level		0.8Vp-p		0.8Vp-p			
	(Clipped Sine Wave)		-	υ.ονρ-ρ	-		
Output Level (Output Level (HCMOS)						
Output High (Logic "1")		2.97V	-				
Output Low (Log	Output Low (Logic "0")		0.33V	-	-		
Duty			55%				
Load(Clipped Si	ine Wave)	45% 55% 10KΩ // 10pF					
Load (HCMOS)		15pF			-		
Control Voltage Range		0.51/	0.5)/	0.5)/	0.5)/		
(VCTCXO)		0.5V	2.5V	0.5V	2.5V		
Pulling Range (Pulling Range (VCTCXO)		-	±5.0ppm	-		
Vc Input Impedance (VCTCXO)		±5.0ppm 100kΩ	-	100kΩ	-		
100 Hz		-115dBc/Hz					
Phase Noise @ 13.0 MHz	1 kHz	-135dBc/Hz					
	10 kHz	-148dBc/Hz					
Start-up Time		2ms max.					
Storage Temp.	Range	-55°C to +125°C					
2.3.490 .011161		1 00 0 10 1 120 0					

Stability vs. Temperature Range Availability							
	Temperature Range						
Stability in ppm	-20°C to +70°C	-30°C to +85°C	-40°C to +85°C				
±0.5 (with pulling range < 10ppm available)	Available	Conditional (depends on operating frequency; case by case)	Conditional (depends on operating frequency; case by case)				
±1.0	Available	Available	Conditional (depends on operating frequency; case by case)				

Other customized specifications maybe available. Please contact Dynamic Engineers Inc. for further details.